10Gbps Long Wavelength InGaAs PIN PD

P/N: DO262 45um E1



PRELIMINARY DATASHEET



Introduction

This high-performance product is a front side illuminated InGaAs PIN photodiode chip that features a large $45\mu m$ detection window, and a set of ground-signal-ground wire-bonding pads. This product has low capacitance, high responsivity, low dark current and excellent reliability, designed for long wavelength optical receiver applications with date rate up to 10Gbps at wavelength from 1200nm to 1600nm with single mode fiber.

Key Features

- 45µm optical detection window for better optical alignment
- Front-sided contact pads for flexible wire bonding
- Date rate up to 10Gbps
- Excellent low dark current and capacitance
- -40C to 85C operation range
- Highly robust and low-cost 4" IC wafer fab with fast cycle-time
- Deliverable in GCS Known Good Die[™] with 100% testing and inspection
- RoHS compliant

Applications

- 10Gigabit Ethernet
- 8G Fiber Channel
- SONET/SDH OC-192

SPECIFICATIONS (T=25C°)

	Conditions	Min.	Typical	Max.	Unit	Notes
Bandwidth	-5V	8	10	-	GHz	
Wavelength range		910	1310/1550	1650	nm	
Capacitance	-3 V, 1 MHz		0.19	0.22	pF	
Responsivity	@1310 nm	0.85	0.90	-	A/W	
Dark current	-5V	-	1	5	nA	

ABSOLUTE MAXIMUM RATING

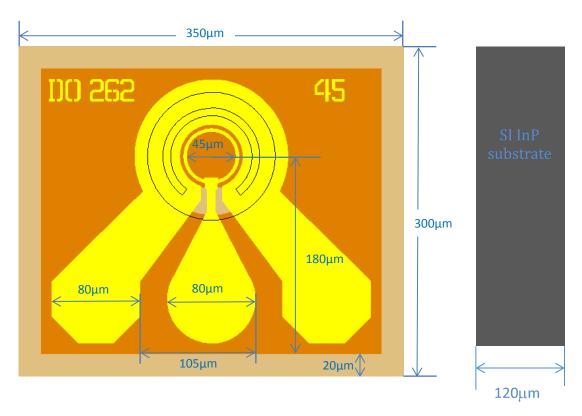
Parameter	Rating		
Operating Temperature	-40C to 85C		
Storage Temperature	-55C to 125C		
Soldering Temperature	260C / 10 sec		

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DIMENSIONSMade in USA

	Conditions	Min.	Typical	Max.	Unit	Notes
Detection window			45		μm	
Bonding pad size			80		μm	Ground pads
			80			Signal pad
Metal height of bond pad		1.4	1.6	-	μm	Au metal
Die height		110	120	130	μm	
Die width		290	300	310	μm	
Die length		340	350	360	μm	



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Attention: InP brittle material and electrostatic sensitive device. Observe precaution for handling.

About GCS:

GCS has a long history manufacturing and shipping both GaAs and InGaAs based photo diodes since 2000. Our state of art manufacturing facility is located in Torrance, California, and has about 10,000 square feet of fab space with a capability of about 1200 4-inch wafers per month and expandable to 2000 wafers per month. GCS as a world-class semiconductor device manufacturer has been delivering a total of over 30 million photo diodes with various date rates and applications used for optical communications, which have been deployed in field by top tier optical transceiver companies worldwide.

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